Complementary Power Transistors

DPAK for Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("1" Suffix)
- Electrically Similar to Popular TIP41 and TIP42 Series
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V _{CEO}	100	Vdc
Collector-Base Voltage	V _{CB}	100	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current – Continuous	I _C	6	Adc
Collector Current – Peak	I _{CM}	10	Adc
Base Current	Ι _Β	2	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	20 0.16	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 These ratings are applicable when surface mounted on the minimum pad sizes recommended.

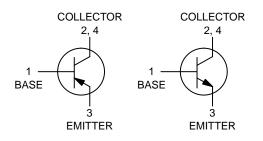


ON Semiconductor®

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SILICON POWER TRANSISTORS 6 AMPERES 100 VOLTS, 20 WATTS

COMPLEMENTARY



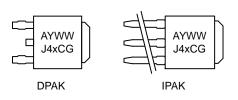


DPAK CASE 369C STYLE 1



IPAK CASE 369D STYLE 1

MARKING DIAGRAMS



A = Assembly Location

′ = Year

WW = Work Week J4xC = Device Code

x = 1 or 2

G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	71.4	°C/W

^{2.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

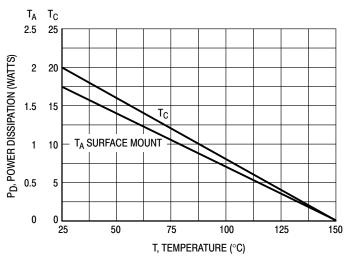
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	1			1
Collector–Emitter Sustaining Voltage (Note 3) (I _C = 30 mAdc, I _B = 0)	V _{CEO(sus)}	100	_	Vdc
Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0)	ICEO	_	50	μAdc
Collector Cutoff Current (V _{CE} = 100 Vdc, V _{EB} = 0)	I _{CES}	_	10	μAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	-	0.5	mAdc
ON CHARACTERISTICS (Note 3)			•	
DC Current Gain $ (I_C = 0.3 \text{ Adc, V}_{CE} = 4 \text{ Vdc}) $ $ (I_C = 3 \text{ Adc, V}_{CE} = 4 \text{ Vdc}) $	h _{FE}	30 15	- 75	-
Collector–Emitter Saturation Voltage (I _C = 6 Adc, I _B = 600 mAdc)	V _{CE(sat)}	_	1.5	Vdc
Base–Emitter On Voltage (I _C = 6 Adc, V _{CE} = 4 Vdc)	V _{BE(on)}	_	2	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain – Bandwidth Product (Note 4) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1 MHz)	f _T	3	-	MHz
Small–Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1 kHz)	h _{fe}	20	_	_

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

4. $f_T = |h_{fe}| \bullet f_{test}$.

TYPICAL CHARACTERISTICS



V_{CC} +30 V $\leq R_{C}$ 25 μs → SCOPE R_{B} D_1 51 $t_r,\,t_f \leq 10\;ns$ **DUTY CYCLE = 1%**

 R_{B} and R_{C} VARIED TO OBTAIN DESIRED CURRENT LEVELS D₁ MUST BE FAST RECOVERY TYPE, e.g.: MSB5300 USED ABOVE $I_B \approx 100 \ mA$ MSD6100 USED BELOW $I_B \approx 100 \ mA$ REVERSE ALL POLARITIES FOR PNP.

Figure 1. Power Derating



500 300 $V_{CE} = 2 V$ 200 T_J = 150°C hFE, DC CURRENT GAIN 100 25°C 70 50 30 - 55°C 20 10 0.3 0.4 0.06 0.1 IC, COLLECTOR CURRENT (AMP)

Figure 2. Switching Time Test Circuit

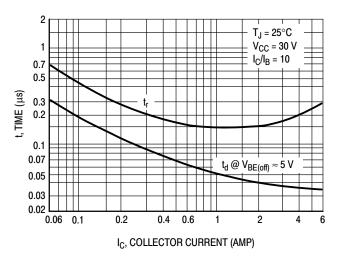
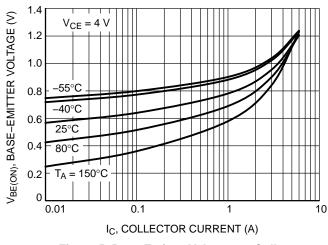


Figure 3. DC Current Gain

Figure 4. Turn-On Time





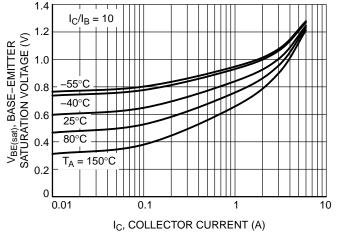


Figure 6. Base Emitter Saturation Voltage vs. **Collector Current**

TYPICAL CHARACTERISTICS

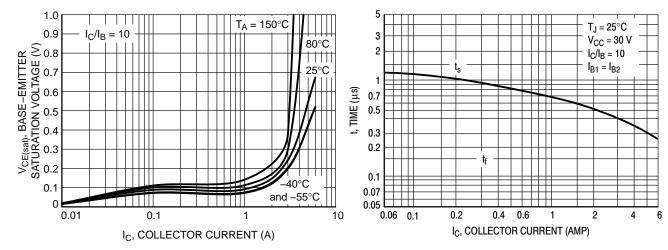


Figure 7. Collector Emitter Saturation Voltage vs. Collector Current

Figure 8. Turn-Off Time

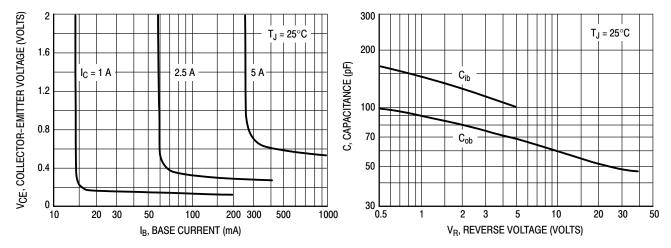


Figure 9. Collector Saturation Region

Figure 10. Capacitance

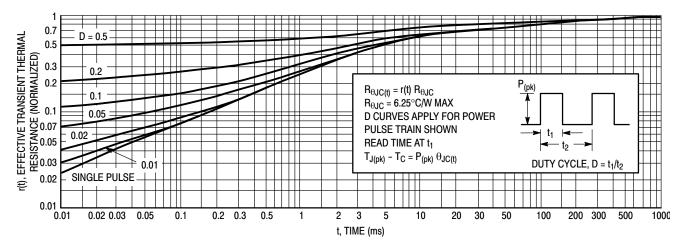


Figure 11. Thermal Response

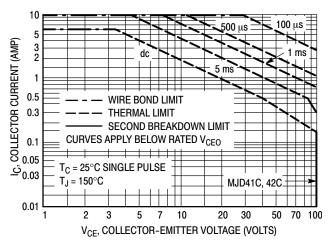


Figure 12. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 12 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 11. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

ORDERING INFORMATION

Device	Package Type	Package	Shipping [†]
MJD41CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel
MJD41CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD41CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
MJD42CG	DPAK (Pb-Free)	369C	75 Units / Rail
MJD42C1G	IPAK (Pb-Free)	369D	75 Units / Rail
MJD42CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel
NJVMJD42CRLG*	DPAK (Pb-Free)	369C	1,800 / Tape & Reel
MJD42CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD42CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure. BRD8011/D.

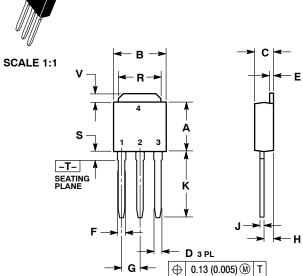
^{*}NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

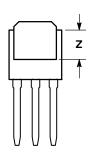
MECHANICAL CASE OUTLINE





DATE 15 DEC 2010





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
٧	0.035	0.050	0.89	1.27
Z	0.155		3.93	

grated rcuits XXXX YWW

ocation.

= Year WW = Work Week

				MARKING DIAGRAMS
STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 3: PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE	STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE	Discrete Circ
STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE 4. ANODE	STYLE 6: PIN 1. MT1 2. MT2 3. GATE 4. MT2	STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		YWW ALY
				xxxxxxxxx = Device Code A = Assembly Lo

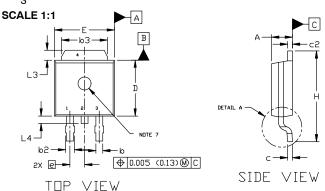
DOCUMENT NUMBER:	98AON10528D	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	IPAK (DPAK INSERTION MOUNT)		PAGE 1 OF 1

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DATE 31 MAY 2023



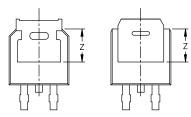


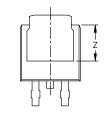
- DIMENSIONING AND TOLERANCING ASME Y14.5M, 1994. CONTROLLING DIMENSION: INCHES
- THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS 63,
- L3. AND Z. L3, AND Z.

 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR
 GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 DIMENSIONS D AND E ARE DETERMINED AT THE
 OUTERMOST EXTREMES OF THE PLASTIC BODY.
 DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
 DETININAL MOLD ESCALUPE.

- OPTIONAL MOLD FEATURE.

DIM	INC	HES	MILLIM	ETERS
MIM	MIN.	MAX.	MIN.	MAX.
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
C	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090	BSC	2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020 BSC		0.51	BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

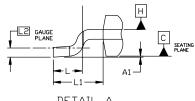




BOTTOM VIEW

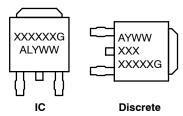
BOTTOM VIEW ALTERNATE CONSTRUCTIONS

5.80 [0.228] 6.20 [0.244] 2.58 3.00 [0.102] [0.118] 1.60 [0.063] 6.17 [0.243]



DETAIL A ROTATED 90° CW

GENERIC MARKING DIAGRAM*



XXXXXX	= Device Code
Α	= Assembly Location
L	= Wafer Lot
Υ	= Year
WW	= Work Week
G	= Pb-Free Package

*This information is generic. Please refer to

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DUWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

3 FMITTER

4. COLLECTOR

s

3 GATE

RECOMMENDED MOUNTING FOOTPRINT*

STYLE 1: STYLE 2: PIN 1. BASE PIN 1. GATE 2. COLLECTOR 2. DRAIL 3. EMITTER 3. SOUF 4. COLLECTOR 4. DRAIL	N 2. CATHODE RCE 3. ANODE	3. GATE	STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE 4. ANODE
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STYLE 7: PIN 1. GATE 2. COLLECTOR STYLE 6: STYLE 8: STYLE 9: STYLE 10: PIN 1. MT1 2. MT2 PIN 1. N/C 2. CATHODE 3. ANODE PIN 1. ANODE 2. CATHODE

4. CATHODE

device data sheet for actual part marking. PIN 1. CATHODE 2. ANODE 3. CATHODE Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may 3 RESISTOR ADJUST not follow the Generic Marking. 4. ANODE

DOCUMENT NUMBER:	98AON10527D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED of the control of	
DESCRIPTION:	DPAK (SINGLE GAUGE)		PAGE 1 OF 1

4. CATHODE

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